

### ORDERING INFORMATION

Temp. Range	Package	Standard Part Number	Lead (Pb)-free Part Number
- 40 °C to 85 °C	16-Pin Plastic DIP	DG213DJ	DG213DJ-E3
	16-Pin Narrow SOIC	DG213DY DG213DY-T1	DG213DY-E3 DG213DY-T1-E3
	16-Pin TSSOP	DG213DQ DG213DQ-T1	DG213DQ-E3 DG213DQ-T1-E3

### ABSOLUTE MAXIMUM RATINGS $T_A = 25\text{ °C}$ , unless otherwise noted

Parameter		Limit	Unit
Voltages Referenced V+ to V-		44	V
GND		25	
Digital Inputs <sup>a</sup> V <sub>S</sub> , V <sub>D</sub>		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first	
Current, Any Terminal		30	mA
Peak Current (Pulsed at 1 ms, 10 % duty cycle max.)		100	
Storage Temperature		- 65 to 125	°C
Power Dissipation <sup>b</sup>	16-Pin Plastic DIP <sup>c</sup>	470	mW
	16-Pin Narrow SOIC <sup>d</sup>	640	
	16-Pin TSSOP <sup>d</sup>	500	

#### Notes:

- Signals on  $S_X$ ,  $D_X$ , or  $IN_X$  exceeding  $V_+$  or  $V_-$  will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- All leads welded or soldered to PC board.
- Derate 6.5 mW/°C above 75 °C.
- Derate 7.6 mW/°C above 75 °C.

**SPECIFICATIONS**

Parameter	Symbol	Test Conditions Unless Otherwise Specified V+ = 15 V, V- = - 15 V, V <sub>L</sub> = 5 V, V <sub>IN</sub> = 2.4 V, 0.8 V <sup>e</sup>	Temp. <sup>a</sup>	D Suffix - 40 °C to 85 °C			Unit
				Min. <sup>c</sup>	Typ. <sup>b</sup>	Max. <sup>c</sup>	
Analog Switch							
Analog Signal Range <sup>d</sup>	V <sub>ANALOG</sub>		Full	V-		V+	V
Drain-Source On-Resistance	r <sub>DS(on)</sub>	V <sub>D</sub> = ± 10 V, I <sub>S</sub> = 1 mA	Room Full		45	60 85	Ω
r <sub>DS(on)</sub> Match	Δr <sub>DS(on)</sub>		Room		1	2	
Source Off Leakage Current	I <sub>S(off)</sub>	V <sub>S</sub> = ± 14 V, V <sub>D</sub> = ± 14 V	Room Full	- 0.5 - 5	± 0.01	0.5 5	nA
Drain Off Leakage Current	I <sub>D(off)</sub>	V <sub>D</sub> = ± 14 V, V <sub>S</sub> = ± 14 V	Room Full	- 0.5 - 5	± 0.01	0.5 5	
Drain On Leakage Current <sup>f</sup>	I <sub>D(on)</sub>	V <sub>S</sub> = V <sub>D</sub> = 14 V	Room Full	- 0.5 - 10	± 0.02	0.5 10	
Digital Control							
Input Voltage High	V <sub>INH</sub>		Full	2.4			V
Input Voltage Low	V <sub>INL</sub>		Full			0.8	
Input Current	I <sub>INL</sub> or I <sub>INH</sub>	V <sub>INH</sub> or V <sub>INL</sub>	Full	- 1		1	μA
Input Capacitance	C <sub>IN</sub>		Room		5		pF
Dynamic Characteristics							
Turn-On Time	t <sub>ON</sub>	V <sub>S</sub> = 10 V See Figure 2	Room		85	130	ns
Turn-Off Time	t <sub>OFF</sub>		Room		55	100	
Break-Before-Make Time Delay	t <sub>D</sub>	V <sub>S</sub> = 10 V, See Figure 3	Room	15	25		
Charge Injection	Q	C <sub>L</sub> = 1000 pF, V <sub>g</sub> = 0 V, R <sub>g</sub> = 0 Ω	Room		1		pC
Source-Off Capacitance	C <sub>S(off)</sub>	V <sub>S</sub> = 0 V, f = 1 MHz	Room		5		pF
Drain-Off Capacitance	C <sub>D(off)</sub>		Room		5		
Channel On Capacitance	C <sub>D(on)</sub>	V <sub>D</sub> = V <sub>S</sub> = 0 V, f = 1 MHz	Room		16		
Off-Isolation	OIRR	C <sub>L</sub> = 15 pF, R <sub>L</sub> = 50 Ω	Room		90		dB
Channel-to-Channel Crosstalk	X <sub>TALK</sub>	V <sub>S</sub> = 1 V <sub>RMS</sub> , f = 100 kHz	Room		95		
Power Supply							
Positive Supply Current	I+	V <sub>IN</sub> = 0 or 5 V	Room Full			1 5	μA
Negative Supply Current	I-		Room Full	- 1 - 5			
Logic Supply Current	I <sub>L</sub>		Room Full			1 5	
Power Supply Range for Continuous Operation	V <sub>OP</sub>		Full	± 3		± 22	V

SPECIFICATIONS for Unipolar Supply							
Parameter	Symbol	Test Conditions Unless Otherwise Specified V <sub>+</sub> = 12 V, V <sub>-</sub> = 0 V, V <sub>L</sub> = 5 V, V <sub>IN</sub> = 2.4 V, 0.8 V <sup>e</sup>	Temp. <sup>a</sup>	D Suffix - 40 °C to 85 °C			Unit
				Min. <sup>c</sup>	Typ. <sup>b</sup>	Max. <sup>c</sup>	
Analog Switch							
Analog Signal Range <sup>d</sup>	V <sub>ANALOG</sub>		Full	V-		V+	V
Drain-Source On-Resistance	r <sub>DS(on)</sub>	V <sub>D</sub> = 3 V, I <sub>S</sub> = 1 mA	Room Full		90	110 140	Ω
Dynamic Characteristics							
Turn-On Time	t <sub>ON</sub>	See Figure 2	Room		125	200	ns
Turn-Off Time	t <sub>OFF</sub>		Room		45	100	
Break-Before-Make Time Delay	t <sub>D</sub>	V <sub>S</sub> = 8 V, See Figure 3	Room	50	80		
Charge Injection	Q	C <sub>L</sub> = 1 nF, V <sub>gen</sub> = 6 V, R <sub>gen</sub> = 0 Ω	Room		4		pC
Power Supply							
Positive Supply Current	I <sub>+</sub>	V <sub>IN</sub> = 0 or 5 V	Room Full			1 5	μA
Negative Supply Current	I <sub>-</sub>		Room Full	- 1 - 5			
Logic Supply Current	I <sub>L</sub>		Room Full			1 5	
Power Supply Range for Continuous Operation	V <sub>OP</sub>		Full	+ 3		+ 40	V

## Notes:

a. Room = 25 °C, Full = as determined by the operating suffix.

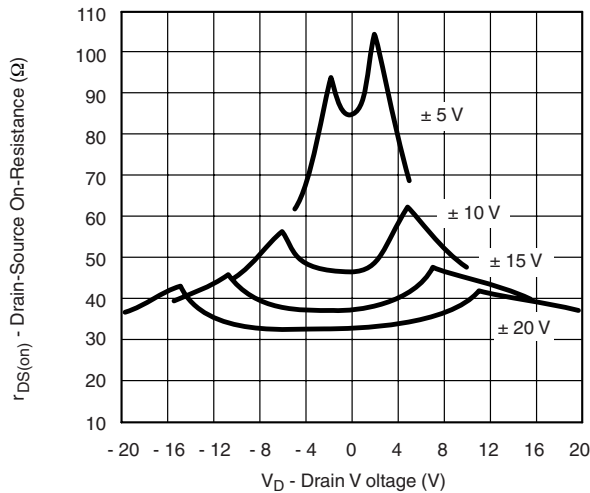
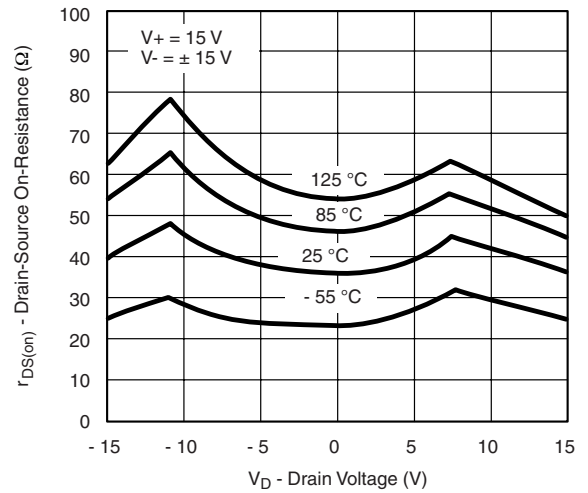
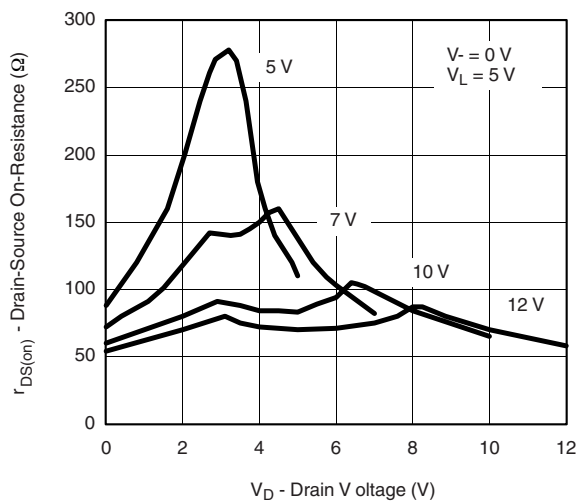
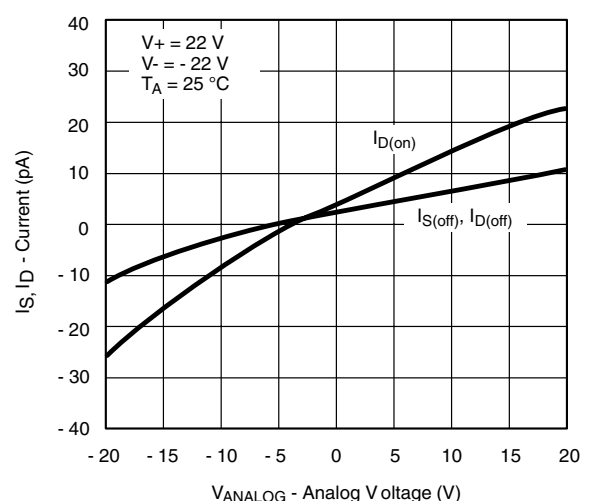
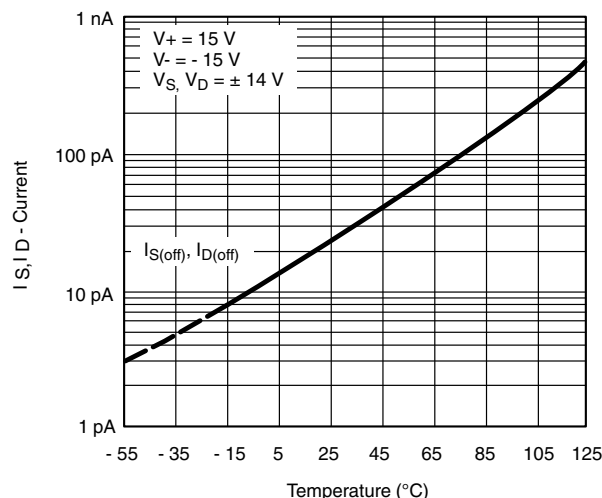
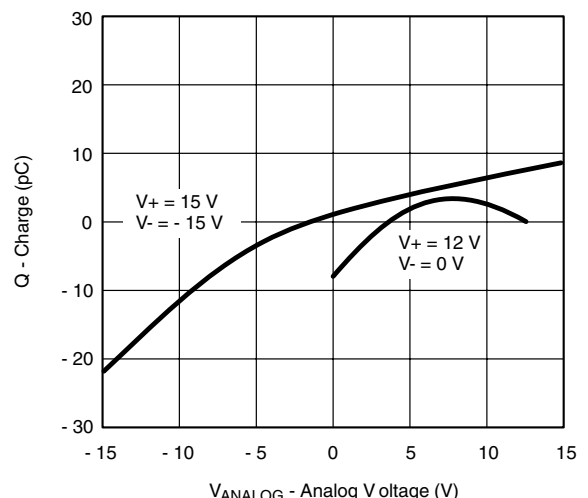
b. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

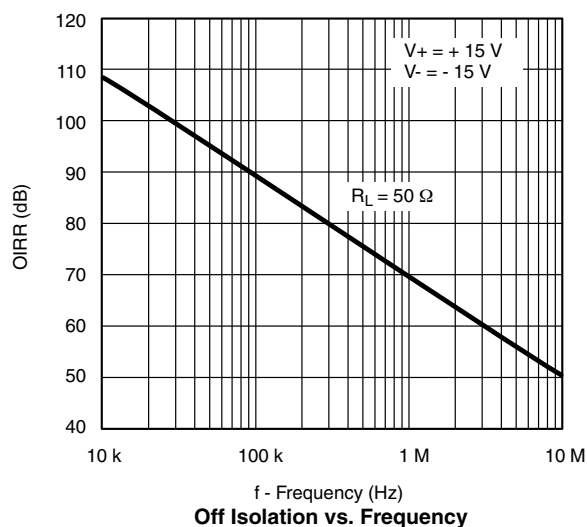
d. Guarantee by design, nor subjected to production test.

e.  $V_{IN}$  = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**TYPICAL CHARACTERISTICS**  $T_A = 25^\circ\text{C}$ , unless otherwise noted

 **$r_{DS(on)}$  vs.  $V_D$  and Power Supply Voltages**

 **$r_{DS(on)}$  vs.  $V_D$  and Temperature**

 **$r_{DS(on)}$  vs.  $V_D$  and Single Power Supply Voltages**

**Leakage Currents vs. Analog Voltage**

**Leakage Current vs. Temperature**

 **$Q_S$ ,  $Q_D$  - Charge Injection vs. Analog Voltage**

## TYPICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$ , unless otherwise noted



## SCHEMATIC DIAGRAM Typical Channel

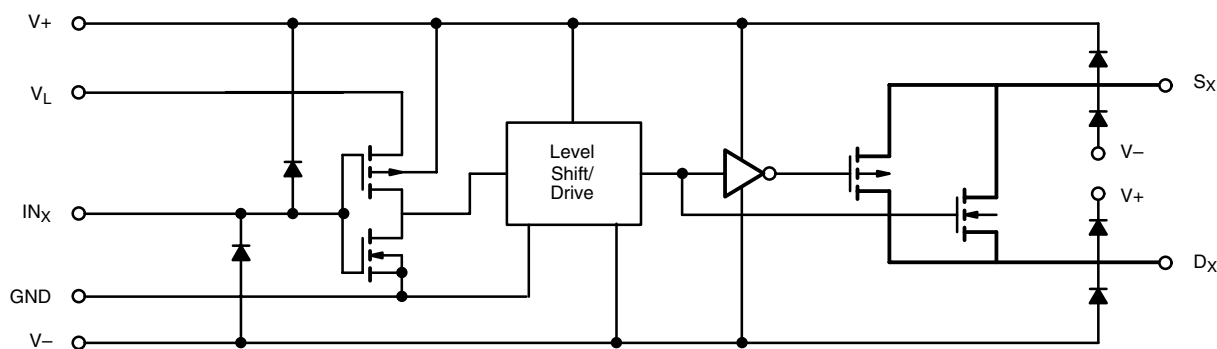


Figure 1.

## TEST CIRCUITS

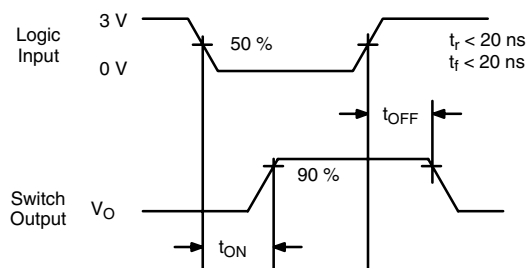
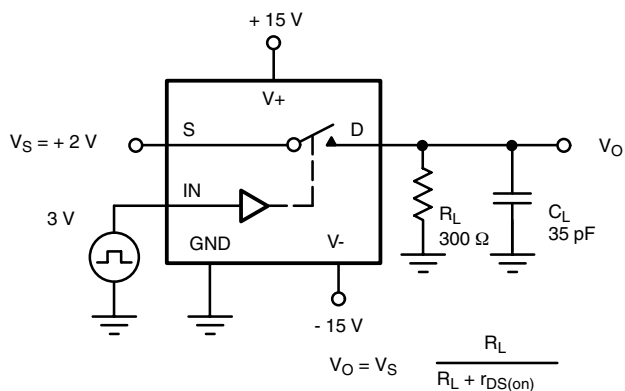
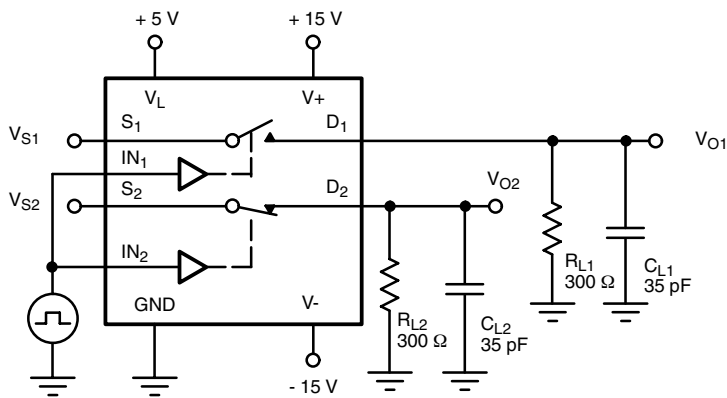
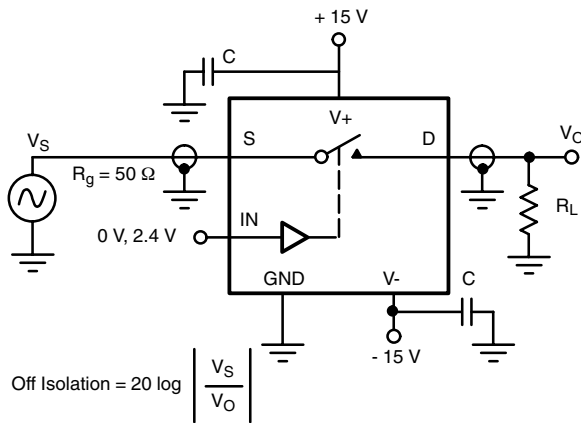
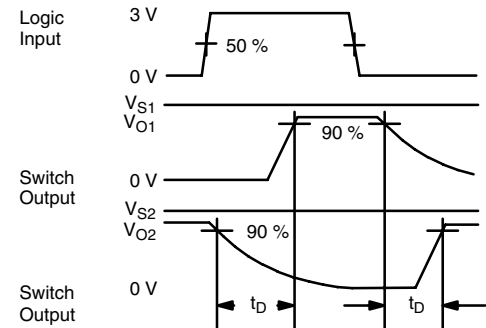
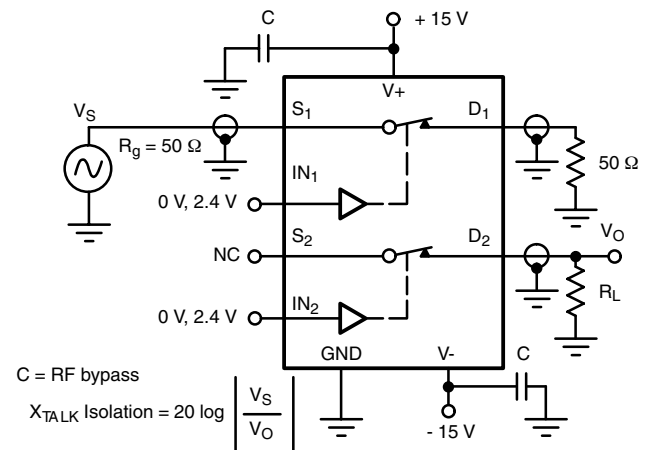
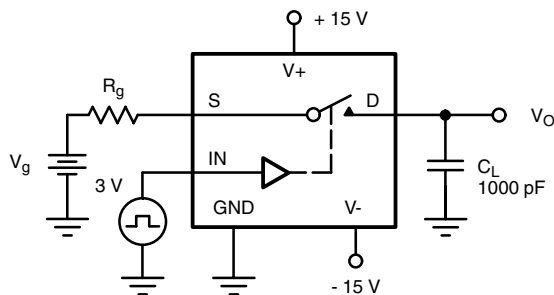
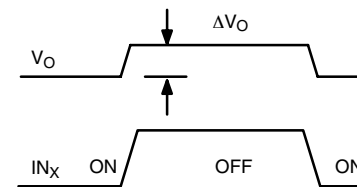


Figure 2. Switching Time

**TEST CIRCUITS**


$C_L$  (includes fixture and stray capacitance)

**Figure 3. Break-Before-Make**

**Figure 4. Off Isolation**

**Figure 5. Channel-to-Channel Crosstalk**

**Figure 6. Charge Injection**


$\Delta V_O$  = measured voltage error due to charge injection  
The charge injection in coulombs is  $Q = C_L \times \Delta V_O$

## APPLICATIONS

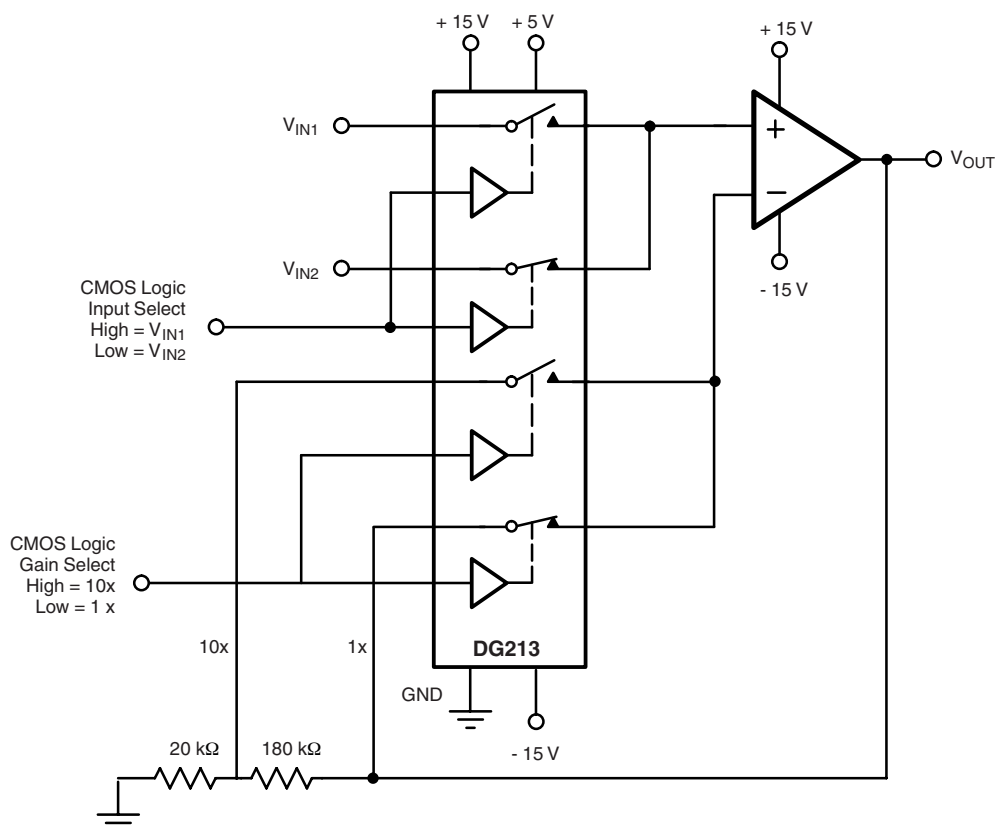


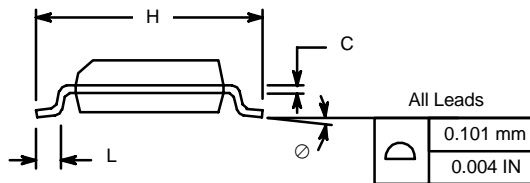
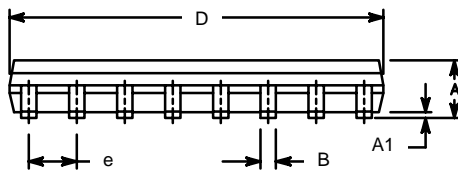
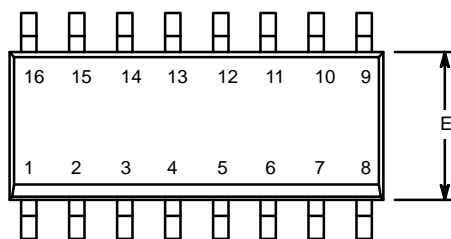
Figure 7. Low Power Non-Inverting Amplifier with Digitally Selectable Inputs and Gain

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### SOIC (NARROW): 16-LEAD

JEDEC Part Number: MS-012



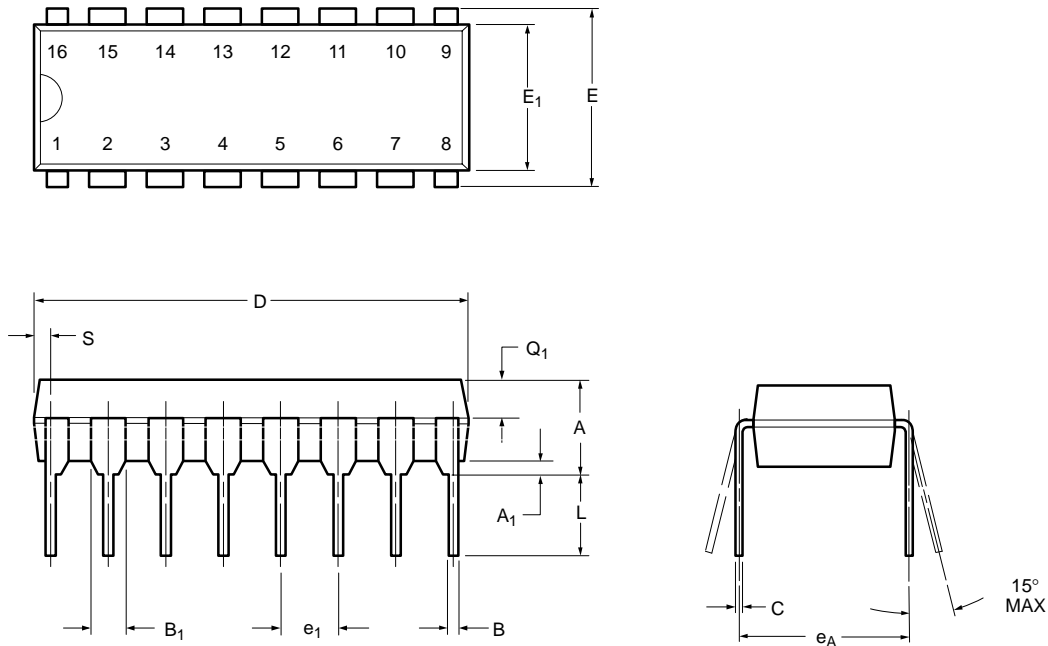
Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A <sub>1</sub>	0.10	0.20	0.004	0.008
B	0.38	0.51	0.015	0.020
C	0.18	0.23	0.007	0.009
D	9.80	10.00	0.385	0.393
E	3.80	4.00	0.149	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
L	0.50	0.93	0.020	0.037
Ø	0°	8°	0°	8°

ECN: S-03946—Rev. F, 09-Jul-01  
DWG: 5300





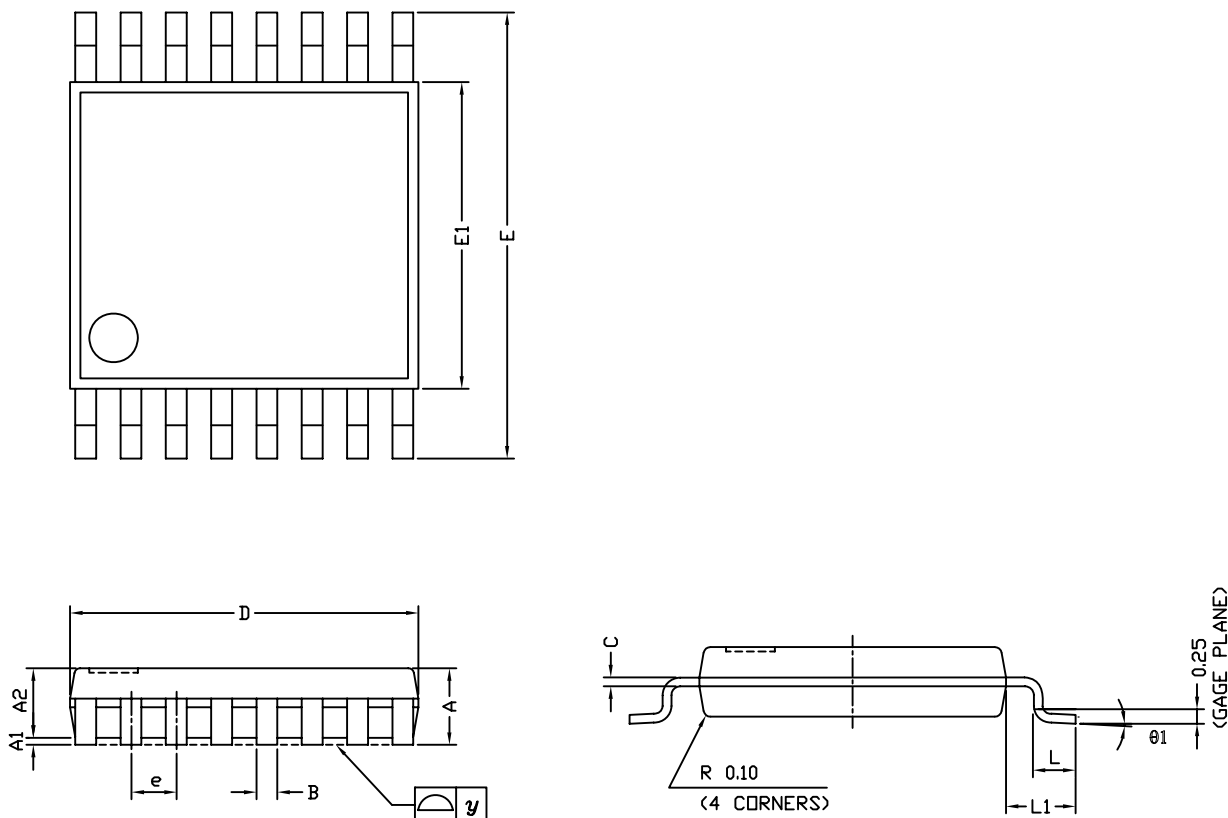
**PDIP: 16-LEAD**



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	3.81	5.08	0.150	0.200
A <sub>1</sub>	0.38	1.27	0.015	0.050
B	0.38	0.51	0.015	0.020
B <sub>1</sub>	0.89	1.65	0.035	0.065
C	0.20	0.30	0.008	0.012
D	18.93	21.33	0.745	0.840
E	7.62	8.26	0.300	0.325
E <sub>1</sub>	5.59	7.11	0.220	0.280
e <sub>1</sub>	2.29	2.79	0.090	0.110
e <sub>A</sub>	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
Q <sub>1</sub>	1.27	2.03	0.050	0.080
S	0.38	1.52	.015	0.060

ECN: S-03946—Rev. D, 09-Jul-01  
DWG: 5482

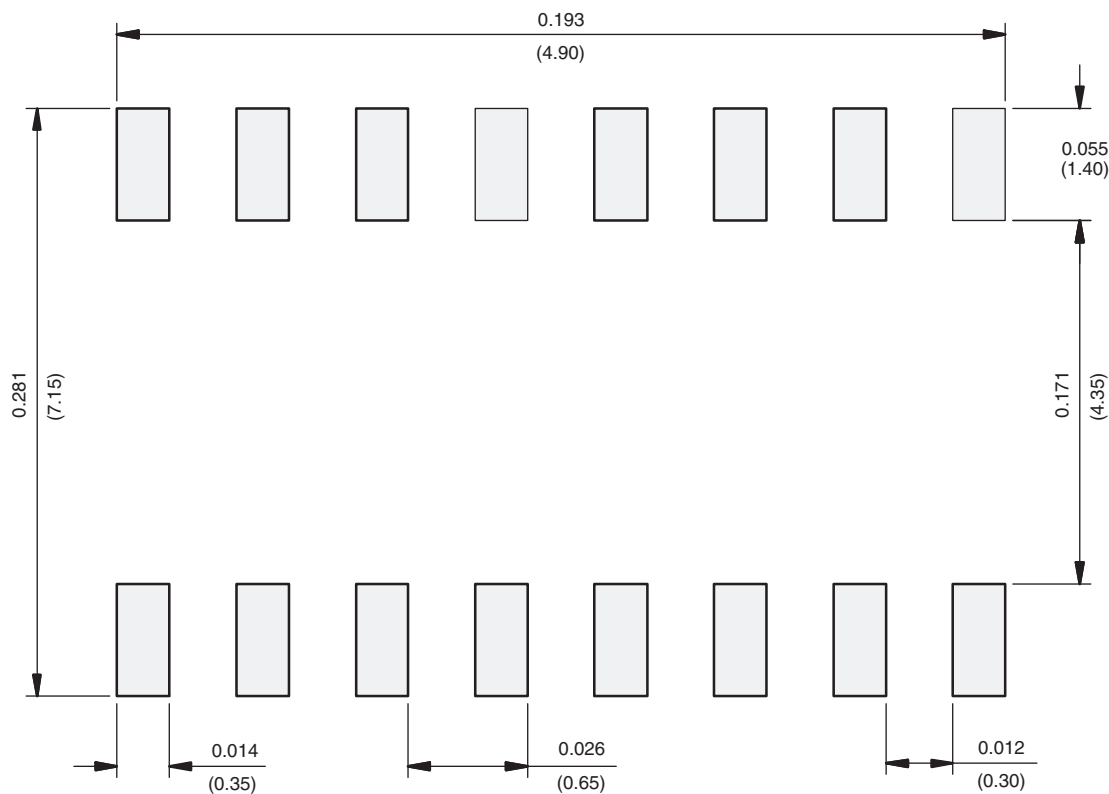
## TSSOP: 16-LEAD



Symbols	DIMENSIONS IN MILLIMETERS		
	Min	Nom	Max
A	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
B	0.22	0.28	0.38
C	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
e	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
y	-	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D, 23-Oct-06			
DWG: 5624			

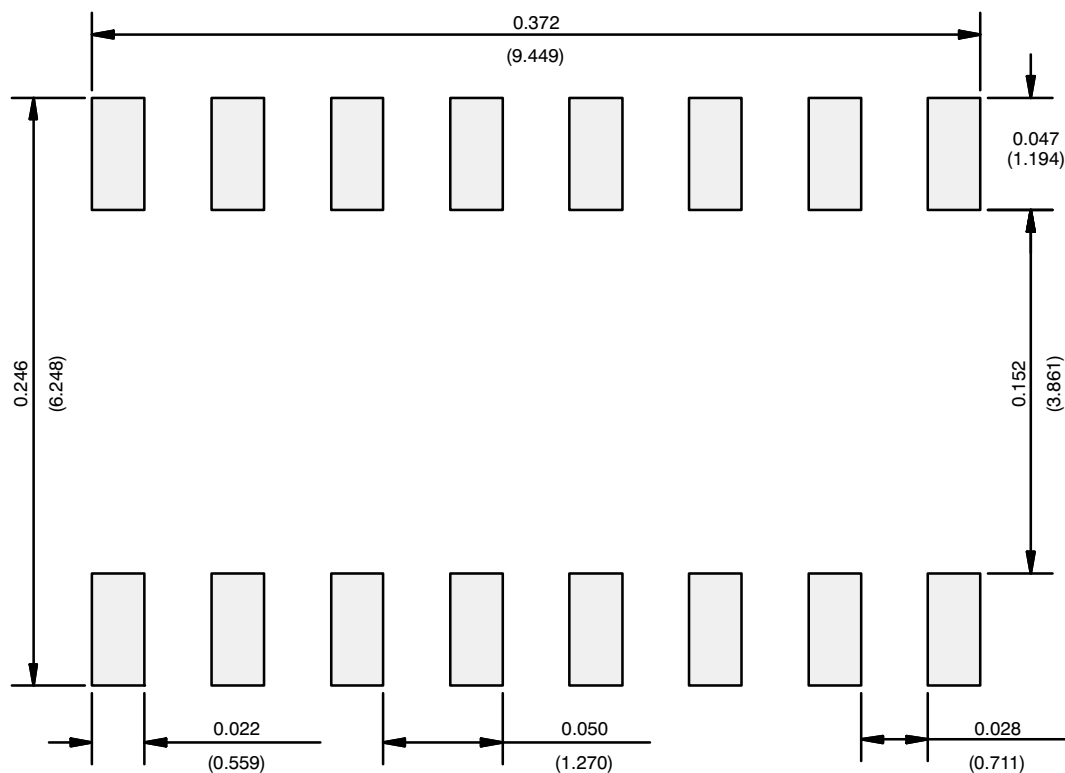


## RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads  
Dimensions in inches (mm)

## RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads  
Dimensions in Inches/(mm)

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